



Leading Innovation >>>

Toshiba Memory America, Inc.

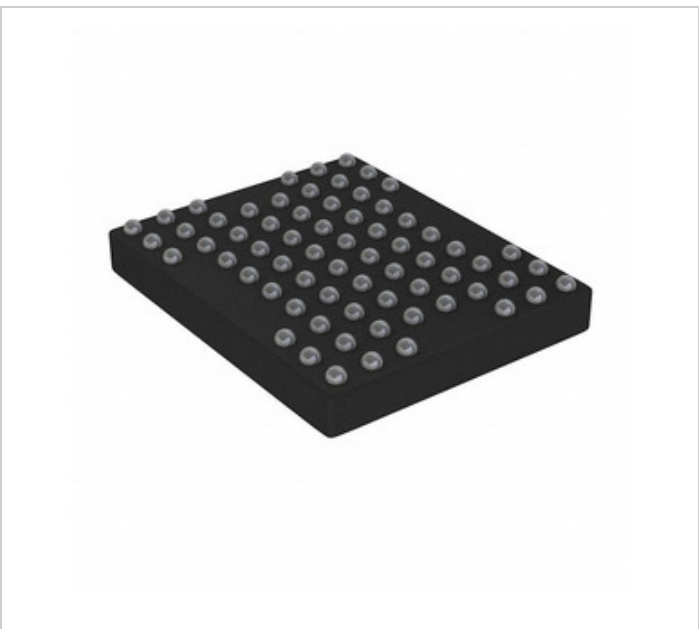


Image may be representation. See specifications for product details.

TC58BYG2S0HBAI6

Part Number:	TC58BYG2S0HBAI6
Manufacturer/Brand:	Toshiba Memory America, Inc.
Product description	IC FLASH 4G PARALLEL 67VFBGA
Datasheets:	 TC58BYG2S0HBAI6.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	16088 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

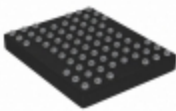
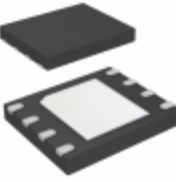
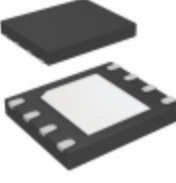
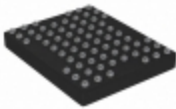
Specifications of TC58BYG2S0HBAI6

PART NUMBER	TC58BYG2S0HBAI6
MANUFACTURER	Toshiba Memory America, Inc.
DESCRIPTION	IC FLASH 4G PARALLEL 67VFBGA
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	16088 pcs
DATA SHEET	 TC58BYG2S0HBAI6.pdf
WRITE CYCLE TIME - WORD, PAGE	25ns
VOLTAGE - SUPPLY	1.7 V ~ 1.95 V
TECHNOLOGY	FLASH - NAND (SLC)
SUPPLIER DEVICE PACKAGE	67-VFBGA (6.5x8)
SERIES	Benand™
PACKAGING	Tray
PACKAGE / CASE	67-VFBGA
OTHER NAMES	TC58BYG2S0HBAI6JDH TC58BYG2S0HBAI6YCL
OPERATING TEMPERATURE	-40°C ~ 85°C (TA)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	4Gb (512M x 8)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	FLASH
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND (SLC) Memory IC 4Gb (512M x 8) Parallel 25ns 67-VFBGA (6.5x8)
ACCESS TIME	25ns

Related Tags

Toshiba Memory America, Inc. TC58BYG2S0HBAI6	TC58BYG2S0HBAI6 Distributor	TC58BYG2S0HBAI6 Supplier
TC58BYG2S0HBAI6 Price	TC58BYG2S0HBAI6 Pictures	TC58BYG2S0HBAI6 Image
TC58BYG2S0HBAI6 PDF Datasheet	TC58BYG2S0HBAI6 Download Datasheet	TC58BYG2S0HBAI6 Datasheet
TC58BYG2S0HBAI6 Stock	Buy TC58BYG2S0HBAI6	Buy Toshiba Memory America, Inc. TC58BYG2S0HBAI6
Toshiba Memory America, Inc. TC58BYG2S0HBAI6	Toshiba Memory America, Inc. Supplier	Toshiba Memory America, Inc. Distributor
Toshiba Memory America, Inc. TC58BYG2S0HBAI6		

Related Products

 Leading Innovation >>> TC58CVG1S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 2GB SERIAL NAND 24NM WSON 3.3V In stock: 20038 pcs RFQ	 TC58BYG1S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 67VFBGA In stock: 24557 pcs RFQ
 Leading Innovation >>> TC58CVG0S3HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 16SOP In stock: 6477 pcs RFQ	 TC58CVG0S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 8WSON In stock: 21309 pcs RFQ
 Leading Innovation >>> TC58BYG1S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 2GB SLC NAND BGA 24NM I TEMP (EE) In stock: 21534 pcs RFQ	 TC58CYG0S3HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 16SOP In stock: 4718 pcs RFQ
 TC58CVG2S0HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G SPI 104MHZ 8WSON In stock: 16041 pcs RFQ	 Leading Innovation >>> TC58CVG2S0HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G SPI 104MHZ 16SOP In stock: 5981 pcs RFQ
 Leading Innovation >>> TC58BYG0S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 1GB SLC NAND BGA 24NM I TEMP (EE) In stock: 27190 pcs RFQ	 TC58BVG2S0HTA10 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 48TSOP I In stock: 19214 pcs RFQ
 TC58BVG2S0HTA00 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 48TSOP I In stock: 18543 pcs RFQ	 TC58BYG0S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 67VFBGA In stock: 30613 pcs RFQ